

BCM62B

PNP/PNP matched double transistor

Rev. 01 — 19 September 2006

Product data sheet

1. Product profile

1.1 General description

PNP/PNP matched double transistor in a SOT143B small Surface-Mounted Device (SMD) plastic package. Matched version of BCV62.

NPN/NPN equivalent: BCM61B.

1.2 Features

- Current gain matching

1.3 Applications

- Current mirror
- Differential amplifier

1.4 Quick reference data

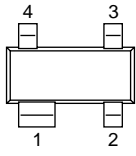
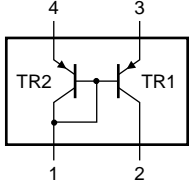
Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------------|---------------------------|---|-------|-----|------|------|
| Per transistor TR1 | | | | | | |
| V_{CEO} | collector-emitter voltage | open base | - | - | -45 | V |
| h_{FE} | DC current gain | $V_{CE} = -5$ V; $I_C = -2$ mA | 200 | 290 | 450 | |
| Per transistor | | | | | | |
| I_C | collector current | | - | - | -100 | mA |
| Per device | | | | | | |
| I_{C1}/I_{E2} | current matching | $V_{CE1} = -5$ V; $I_{E2} = 0.5$ mA; $T_{amb} \leq 25$ °C | [1] 1 | 1.1 | 1.2 | |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|---------------------------------|---|---|
| 1 | collector TR2, base TR1 and TR2 |  |  |
| 2 | collector TR1 | | |
| 3 | emitter TR1 | | |
| 4 | emitter TR2 | | |

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3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| BCM62B | - | plastic surface-mounted package; 4 leads | SOT143B |

4. Marking

Table 4. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| BCM62B | *AD |

- [1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------|---------------------------|----------------------------------|-------|------|------|
| Per transistor TR1 | | | | | |
| V_{CBO} | collector-base voltage | open emitter | - | -50 | V |
| V_{CEO} | collector-emitter voltage | open base | - | -45 | V |
| Per transistor | | | | | |
| V_{EBS} | emitter-base voltage | $V_{CB} = 0$ V | - | -5 | V |
| I_C | collector current | | - | -100 | mA |
| I_{CM} | peak collector current | single pulse; $t_p \leq 1$ ms | - | -200 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C | [1] - | 220 | mW |
| Per device | | | | | |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C | [1] - | 390 | mW |
| T_j | junction temperature | | - | 150 | °C |
| T_{amb} | ambient temperature | | -65 | +150 | °C |
| T_{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------|---|-------------|-------|-----|-----|------|
| Per transistor | | | | | | |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] - | - | 568 | K/W |
| Per device | | | | | | |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] - | - | 321 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|---------------------------|--------------------------------------|---|-----|------|------|---------------|----|
| Per transistor TR1 | | | | | | | |
| I_{CBO} | collector-base cut-off current | $V_{CB} = -30\text{ V};$ $I_E = 0\text{ A}$ | - | - | -15 | nA | |
| | | $V_{CB} = -30\text{ V};$ $I_E = 0\text{ A};$ $T_j = 150\text{ }^{\circ}\text{C}$ | - | - | -5 | μA | |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = -5\text{ V};$ $I_C = 0\text{ A}$ | - | - | -100 | nA | |
| h_{FE} | DC current gain | $V_{CE} = -5\text{ V};$ $I_C = -10\text{ }\mu\text{A}$ | - | 250 | - | | |
| | | $V_{CE} = -5\text{ V};$ $I_C = -100\text{ }\mu\text{A}$ | 100 | - | - | | |
| | | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | 200 | 290 | 450 | | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = -10\text{ mA};$ $I_B = -0.5\text{ mA}$ | - | -50 | -200 | mV | |
| | | $I_C = -100\text{ mA};$ $I_B = -5\text{ mA}$ | - | -200 | -400 | mV | |
| V_{BEsat} | base-emitter saturation voltage | $I_C = -10\text{ mA};$ $I_B = -0.5\text{ mA}$ | [1] | - | -760 | mV | |
| | | $I_C = -100\text{ mA};$ $I_B = -5\text{ mA}$ | [1] | - | -920 | mV | |
| V_{BE} | base-emitter voltage | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | [2] | -600 | -650 | -700 | mV |
| | | $V_{CE} = -5\text{ V};$ $I_C = -10\text{ mA}$ | [2] | - | - | -760 | mV |
| C_c | collector capacitance | $V_{CB} = -10\text{ V};$ $I_E = i_e = 0\text{ A};$ $f = 1\text{ MHz}$ | - | - | 2.2 | pF | |
| C_e | emitter capacitance | $V_{EB} = -0.5\text{ V};$ $I_C = i_c = 0\text{ A};$ $f = 1\text{ MHz}$ | - | 10 | - | pF | |
| f_T | transition frequency | $V_{CE} = -5\text{ V};$ $I_C = -10\text{ mA};$ $f = 100\text{ MHz}$ | 100 | 175 | - | MHz | |
| NF | noise figure | $V_{CE} = -5\text{ V};$ $I_C = -0.2\text{ mA};$ $R_S = 2\text{ k}\Omega;$ $f = 10\text{ Hz to}$ 15.7 kHz | - | 1.6 | - | dB | |
| | | $V_{CE} = -5\text{ V};$ $I_C = -0.2\text{ mA};$ $R_S = 2\text{ k}\Omega;$ $f = 1\text{ kHz};$ $B = 200\text{ Hz}$ | - | 3.1 | - | dB | |

Table 7. Characteristics ...continued $T_{amb} = 25\text{ °C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------------|----------------------|---|----------|------|------|------|
| Per transistor TR2 | | | | | | |
| V_{EBS} | emitter-base voltage | $V_{CB} = 0\text{ V};$ $I_E = 250\text{ mA}$ | - | - | 1.5 | V |
| | | $V_{CB} = 0\text{ V};$ $I_E = 10\text{ }\mu\text{A}$ | 400 | - | - | mV |
| Per device | | | | | | |
| I_{C1}/I_{E2} | current matching | $V_{CE1} = -5\text{ V};$ $I_{E2} = 0.5\text{ mA};$ $T_{amb} \leq 25\text{ °C}$ | [3] 1 | 1.1 | 1.2 | |
| | | $V_{CE1} = -5\text{ V};$ $I_{E2} = 0.5\text{ mA};$ $T_{amb} \leq 150\text{ °C}$ | [3] 1.02 | - | 1.22 | |
| | | $V_{CE1} = -3\text{ V};$ $I_{E2} = 0.5\text{ mA};$ $T_{amb} \leq 25\text{ °C}$ | [3] 0.95 | 1.05 | 1.15 | |
| | | $V_{CE1} = -1\text{ V};$ $I_{E2} = 0.5\text{ mA};$ $T_{amb} \leq 25\text{ °C}$ | [3] 0.9 | 1 | 1.1 | |

[1] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.[2] V_{BE} decreases by about 2 mV/K with increasing temperature.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

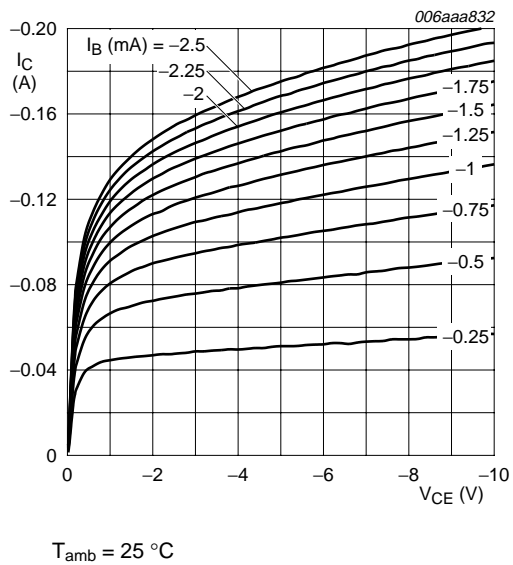


Fig 1. Collector current as a function of collector-emitter voltage; typical values

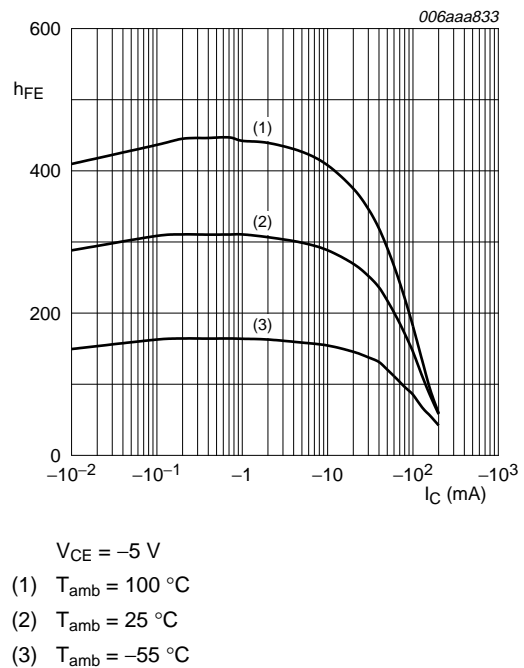


Fig 2. DC current gain as a function of collector current; typical values

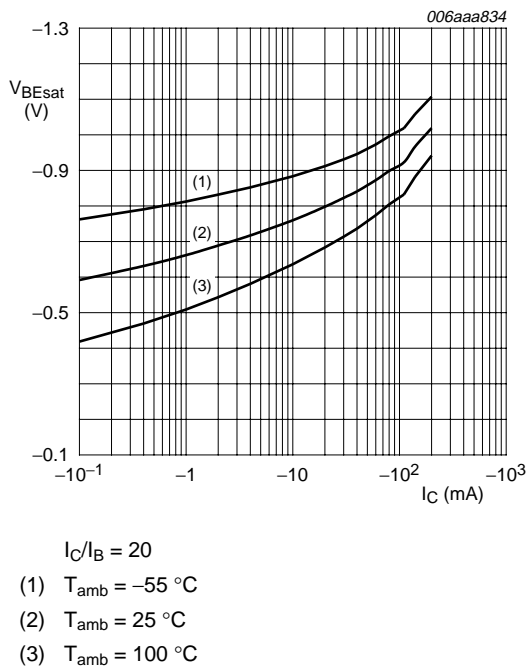


Fig 3. Base-emitter saturation voltage as a function of collector current; typical values

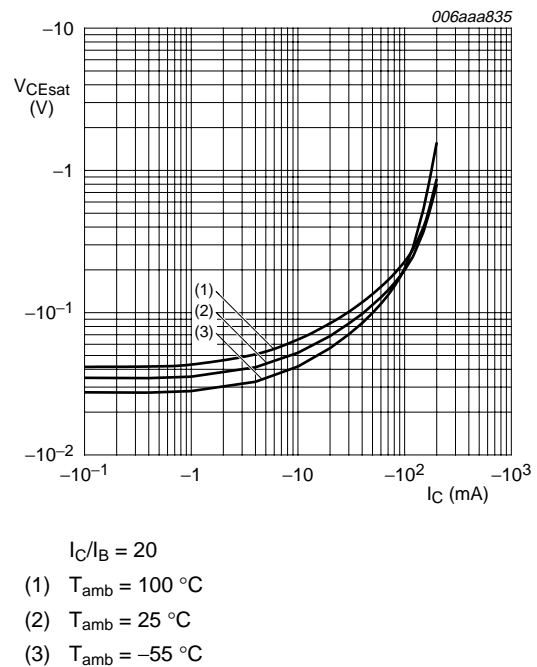
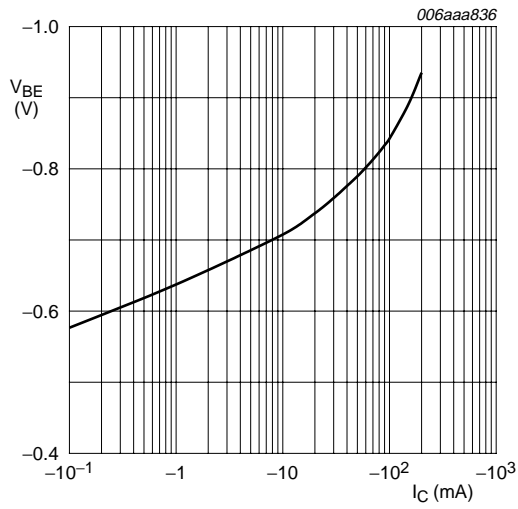
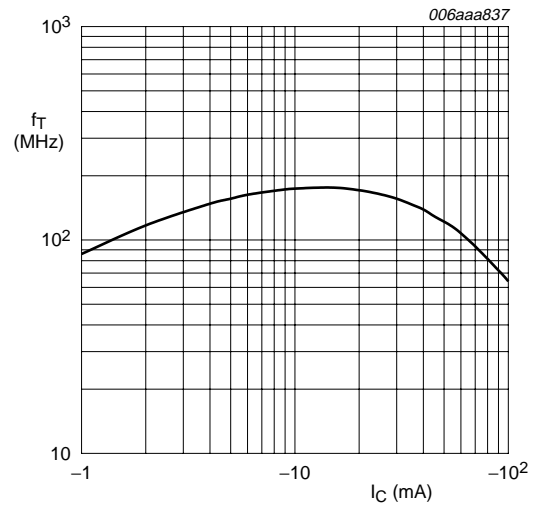


Fig 4. Collector-emitter saturation voltage as a function of collector current; typical values



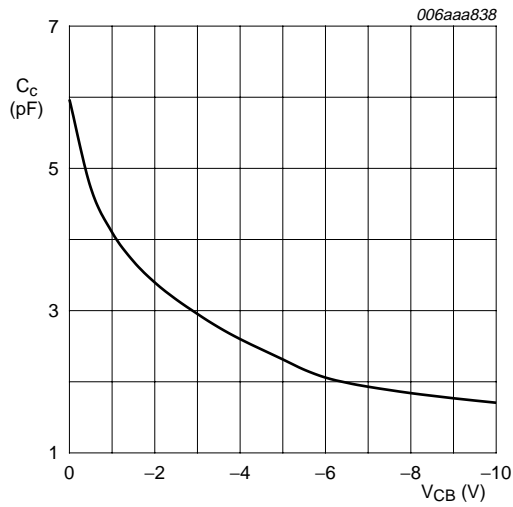
$V_{CE} = -5$ V; $T_{amb} = 25$ °C

Fig 5. Base-emitter voltage as a function of collector current; typical values



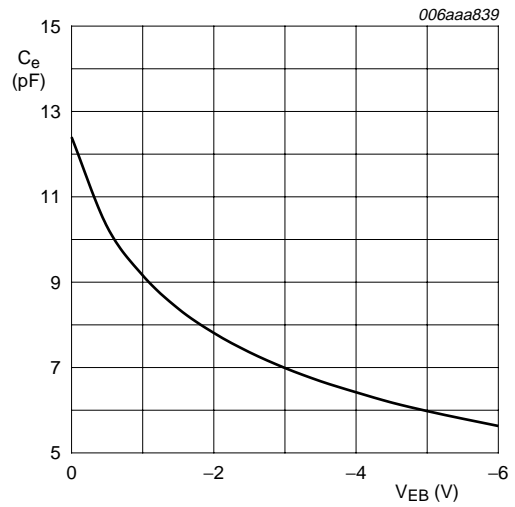
$V_{CE} = -5$ V; $T_{amb} = 25$ °C

Fig 6. Transition frequency as a function of collector current; typical values



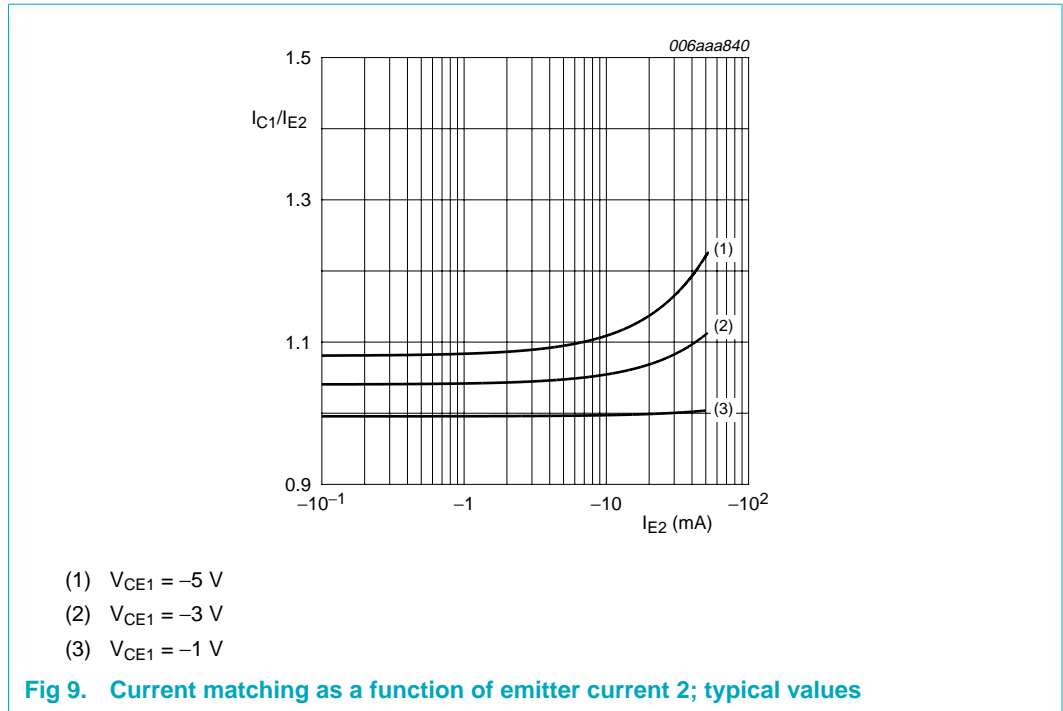
$f = 1$ MHz; $T_{amb} = 25$ °C

Fig 7. Collector capacitance as a function of collector-base voltage; typical values

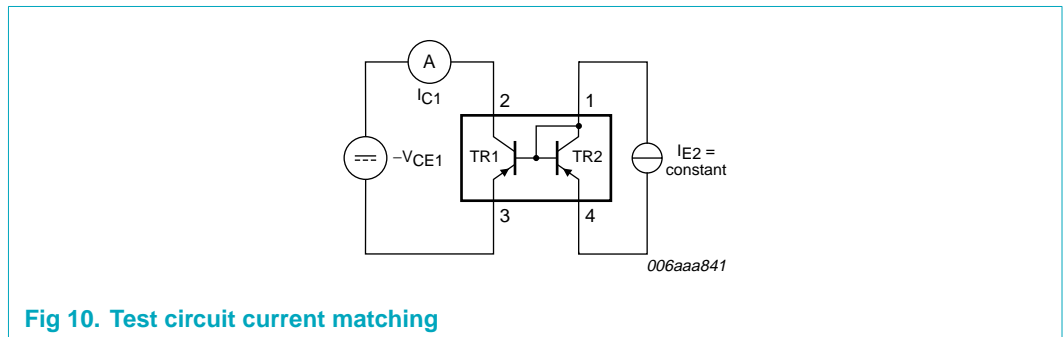


$f = 1$ MHz; $T_{amb} = 25$ °C

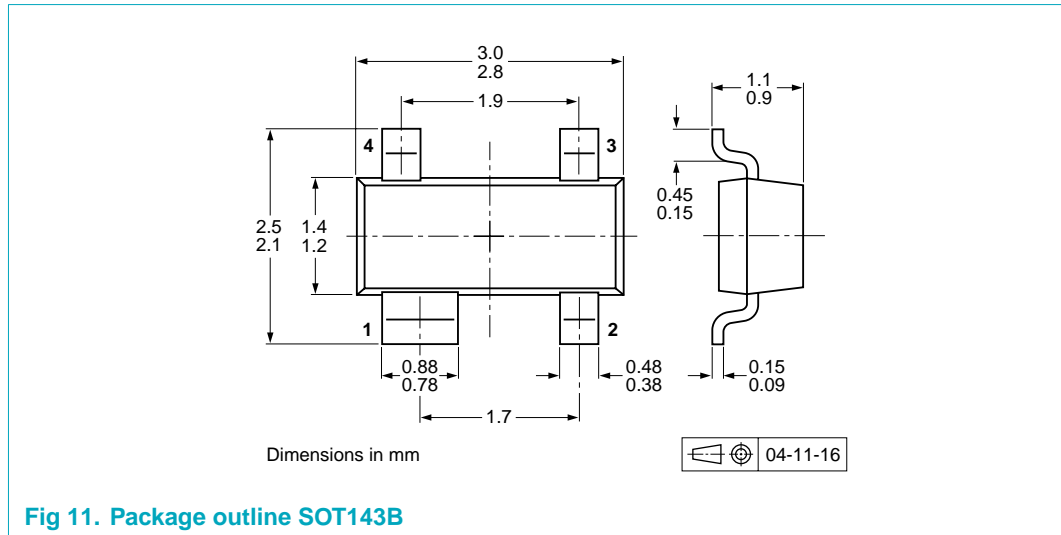
Fig 8. Emitter capacitance as a function of emitter-base voltage; typical values



8. Test information



9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

| Type number | Package | Description | Packing quantity | |
|-------------|---------|--------------------------------|------------------|-------|
| | | | 3000 | 10000 |
| BCM62B | SOT143B | 4 mm pitch, 8 mm tape and reel | -215 | -235 |

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering

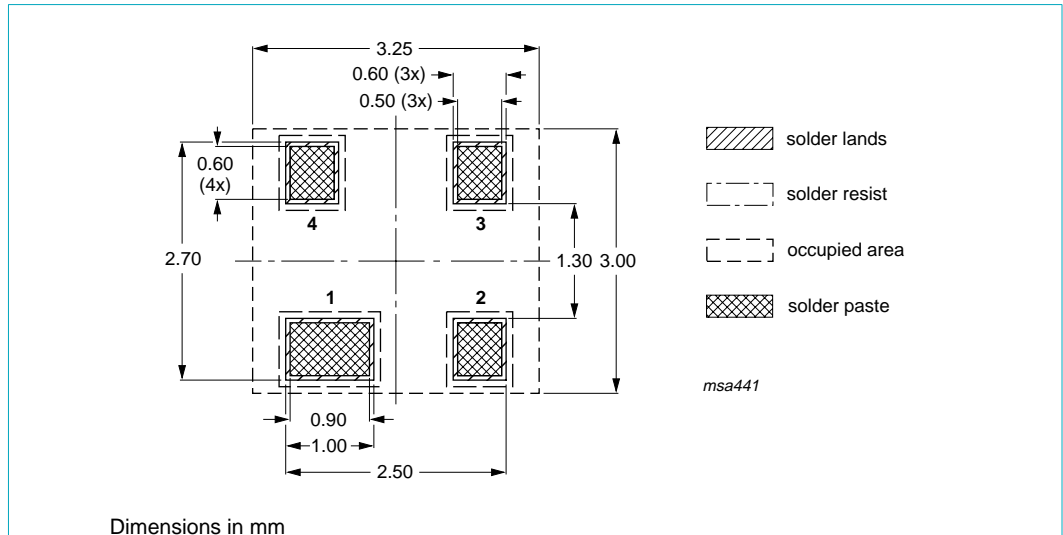


Fig 12. Reflow soldering footprint SOT143B

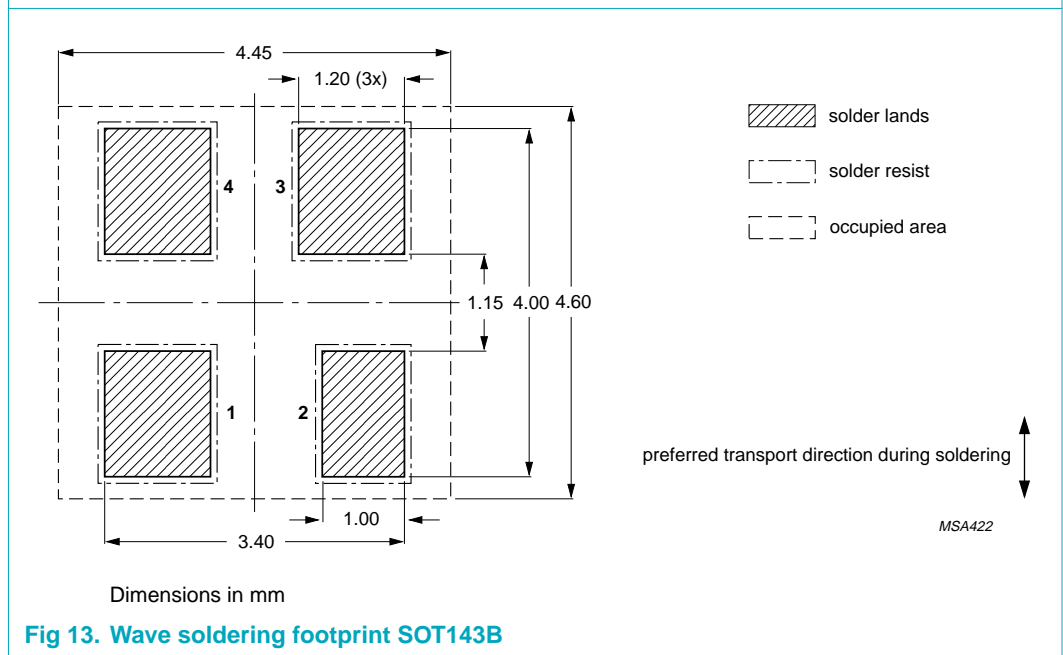


Fig 13. Wave soldering footprint SOT143B

12. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| BCM62B_1 | 20060919 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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